

FEATURES

Plastic SMD package

· Low leakage current: typ. 3 pA

• Switching time: typ. 0.8 μs

• Continuous reverse voltage: max. 75 V

Cathode Anode

APPLICATION

 Low-leakage current applications in surface mounted circuits.

SOD-323

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT			
Per diode								
V_{RRM}	repetitive peak reverse voltage	3	_	85	V			
V _R	continuous reverse voltage			75	V			
l _E	continuous forward current	single diode loaded; note 1; see Fig.2		160	mA			
		double diode loaded; note 1; see Fig.2		140	mA			
I _{FRM}	repetitive peak forward current	J* .1	5	500	mA			
I _{FSM}	non-repetitive peak forward current	square wave; T_j = 25 °C prior to surge; see Fig.4 t_p = 1 μ s t_p = 1 ms t_p = 1 s		4 1 0.5	A A A			
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1	_	250	mW			
T _{stg}	storage temperature		-65	+150	°C			
Tj	junction temperature	121	_	150	°C			

ELECTRICAL CHARACTERISTICS T_j = 25 °C unless otherwise specified.

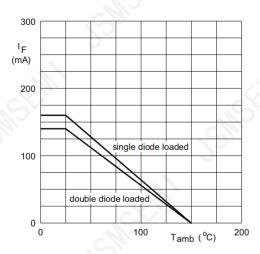
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
Per diode		CX			•
		see Fig.3			
V _F		I _F = 1 mA	C) -	900	m∨
	forward voltage	I _F = 10 mA	3P -	1000	m∨
		I _F = 50 mA	-	1100	mV
		I _F = 150 mA	_	1250	m∨
I _R		see Fig.5			4
	reverse current	V _R = 75 V	0.0033	5	nA
		V _R = 75 V; T _i = 150 °C		80	Α
C _d	diode capacitance	f = 1 MHz; V _R = 0; see Fig.6	2	- 1	pF
t _{rr}	reverse recovery time	when switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ;	0.8	3	μs
41		measured at I _R = 1 mA; see Fig.7			μο

Note

1. Device mounted on a FR4 printed-circuit board.

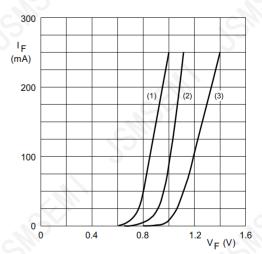


Typical Characteristics



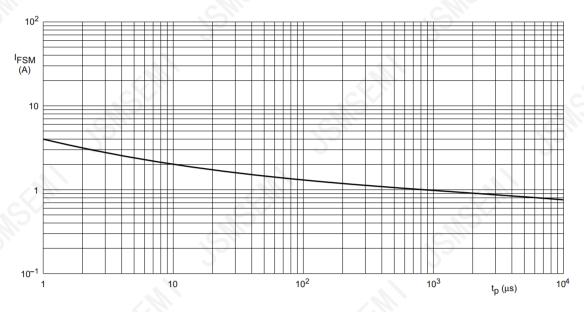
Device mounted on a FR4 printed-circuit board.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.



- (1) T_j = 150 °C; typical values.
- (2) T_j = 25 °C; typical values.
- (3) T_j = 25 °C; maximum values.

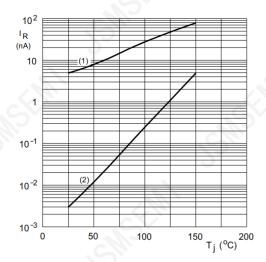
Fig.3 Forward current as a function of forward voltage; per diode.



Based on square wave currents; T_j = 25 °C prior to surge.

Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration per diode.

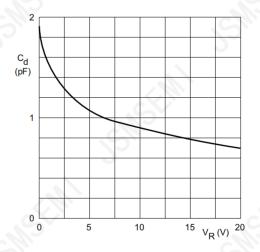
Typical Characteristics





- (1) Maximum values.
- (2) Typical values.

Fig.5 Reverse current as a function of junction temperature; per diode.



f = 1 MHz; T_j = 25 °C.

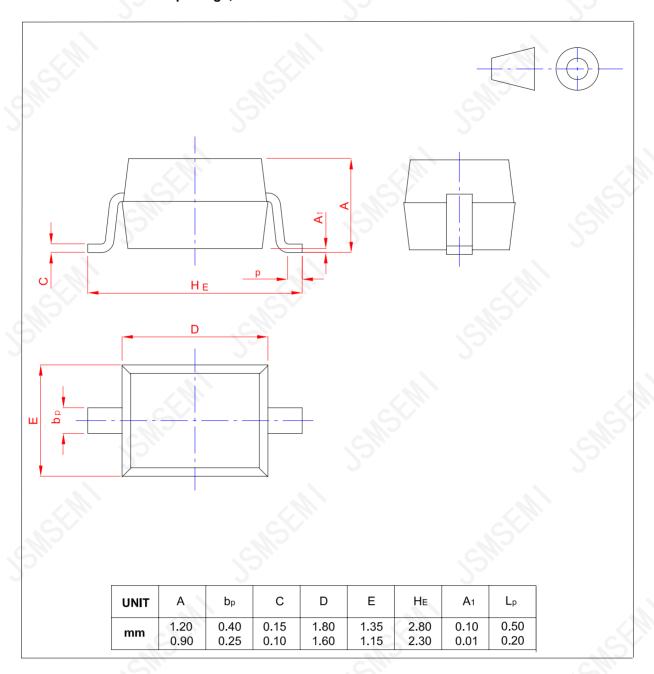
Fig.6 Diode capacitance as a function of reverse voltage; per diode; typical values.



PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323





Revision History

Rev.	Change	Date
V1.0	Initial version	2/23/2024
-11		

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